

Phase-out/Discontinued **μ PA1570**

**N-CHANNEL POWER MOS FET ARRAY
SWITCHING TYPE**

DESCRIPTION

The μ PA1570 is N-channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

FEATURES

- 4 V driving is possible
- Large Current and Low On-state Resistance
 $I_D(\text{pulse}) = \pm 8 \text{ A}$
 $R_{DS(\text{on})} \leq 0.35 \Omega \text{ MAX. } (V_{GS} = 10 \text{ V})$
 $R_{DS(\text{on})} \leq 0.50 \Omega \text{ MAX. } (V_{GS} = 4 \text{ V})$
- 2.54 mm Pitch (0.1 inch)

ORDERING INFORMATION

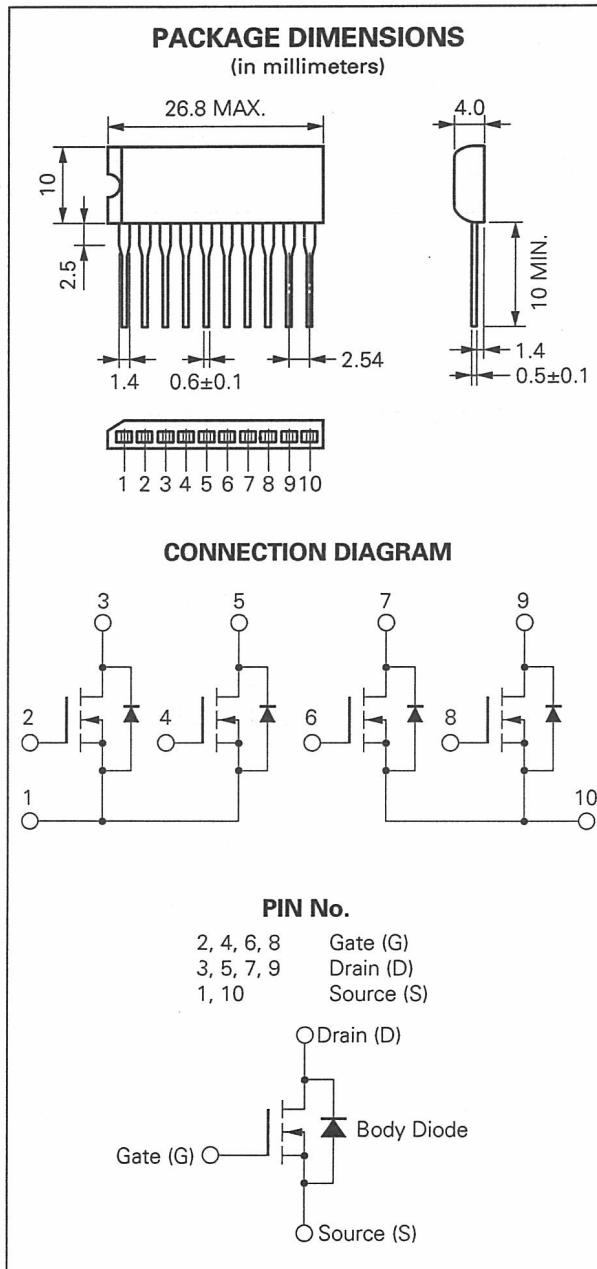
Part Number	Package	Quality Grade
μ PA1570H	10 pin SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

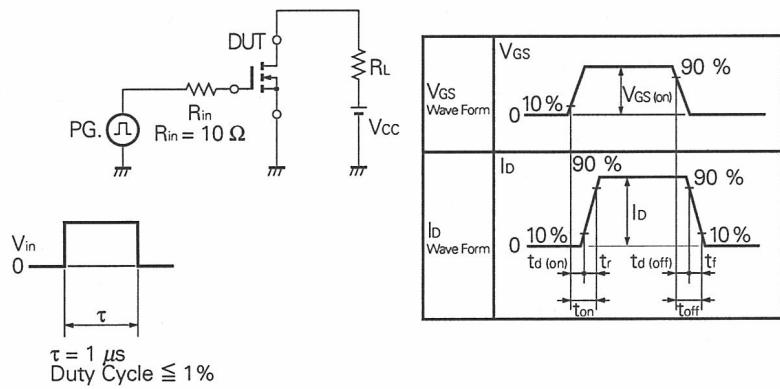
Drain to Source Voltage	V_{DSS}	30	V
Gate to Source Voltage	V_{GSS}	± 20	V
Drain Current (DC)	$I_D(\text{DC})$	± 2.0	A/unit
Drain Current (pulse)	$I_D(\text{pulse})^*$	± 8.0	A/unit
Total Power Dissipation (4 circuits) $< T_c = 25^\circ\text{C} > P_{T1}$		28	W
Total Power Dissipation (4 circuits) $< T_a = 25^\circ\text{C} > P_{T2}$		3.5	W
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Junction Temperature	T_j	150	$^\circ\text{C}$

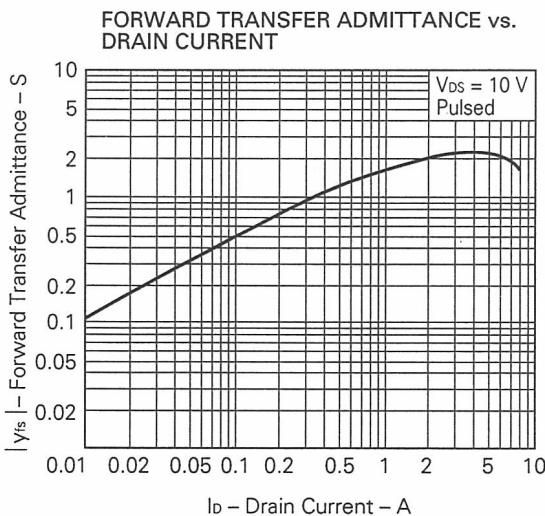
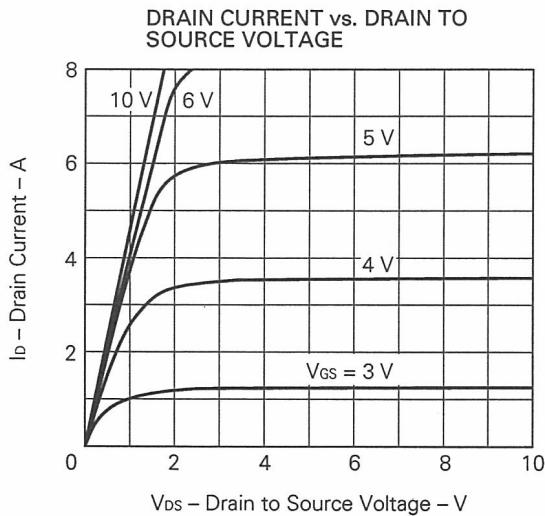
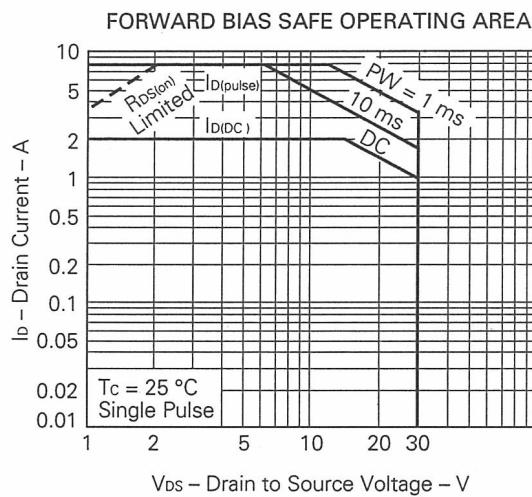
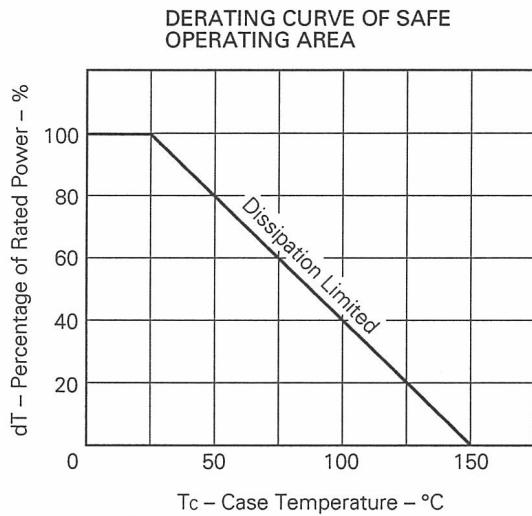
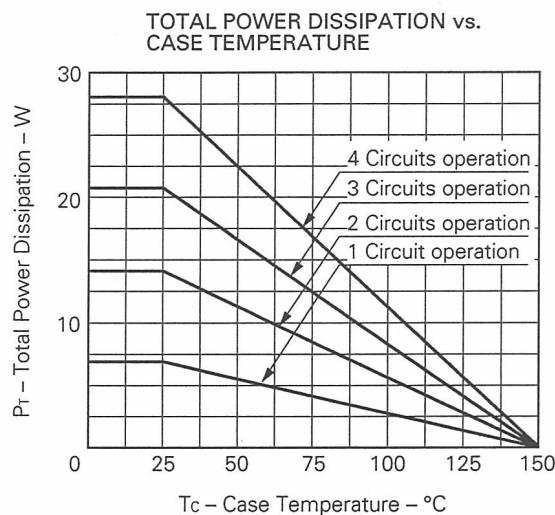
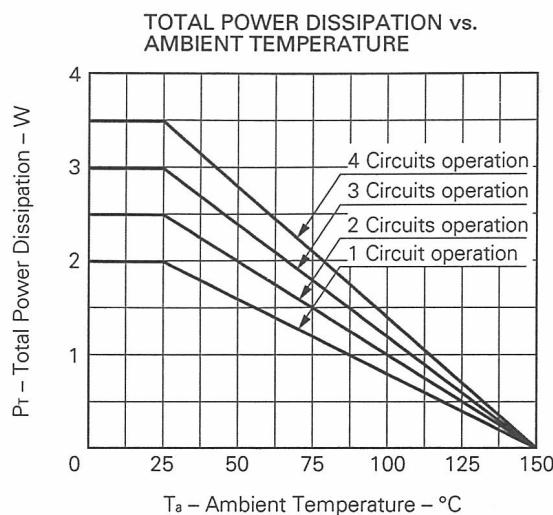
* PW $\leq 300 \mu\text{s}$, Duty Cycle $\leq 10 \%$



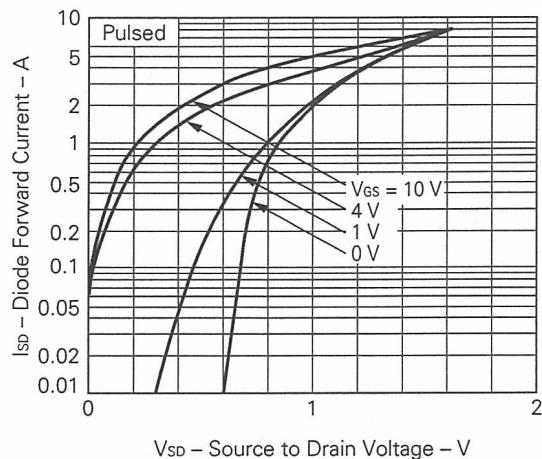
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Leakage Current	I_{DSS}			10	μA	$V_{DS} = 30\text{ V}, V_{GS} = 0$
Gate to Source Leakage Current	I_{GSS}			± 100	nA	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0$
Gate to Source Cutoff Voltage	$V_{GS(off)}$	1.0		2.5	V	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$
Forward Transfer Admittance	$ y_{fs} $	1.0	1.6		S	$V_{DS} = 10\text{ V}, I_D = 1\text{ A}$
Drain to Source On-state Resistance	$R_{DS(on)1}$		0.2	0.35	Ω	$V_{GS} = 10\text{ V}, I_D = 1\text{ A}$
Drain to Source On-state Resistance	$R_{DS(on)2}$		0.35	0.50	Ω	$V_{GS} = 4\text{ V}, I_D = 1.0\text{ A}$
Input Capacitance	C_{iss}		270		pF	$V_{DS} = 10\text{ V}$ $V_{GS} = 0$ $f = 1.0\text{ MHz}$
Output Capacitance	C_{oss}		150		pF	
Reverse Transfer Capacitance	C_{rss}		40		pF	
Turn-On Delay Time	$t_{d(on)}$		30		ns	$I_D = 1\text{ A}$ $V_{GS} = 10\text{ V}$ $V_{CC} = 15\text{ V}$ $R_L = 15\Omega, R_{in} = 10\Omega$ See Fig. 1
Rise Time	t_r		90		ns	
Turn-Off Delay Time	$t_{d(off)}$		400		ns	
Fall Time	t_f		250		ns	

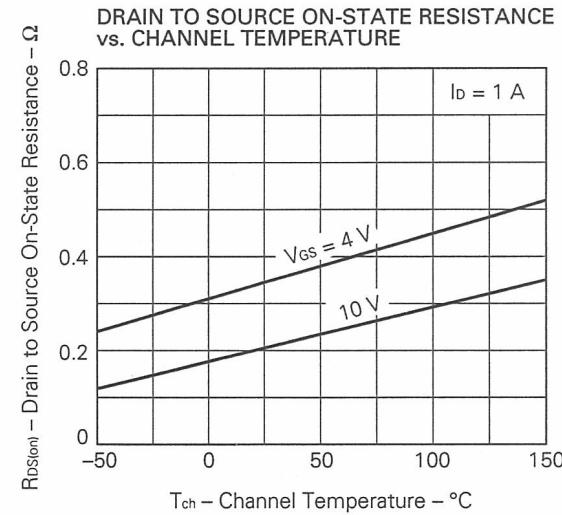
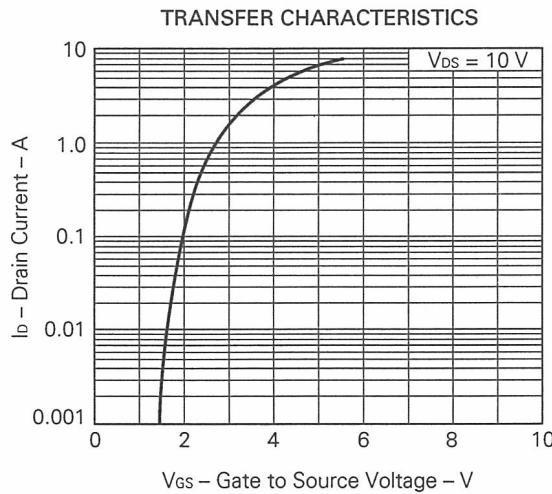
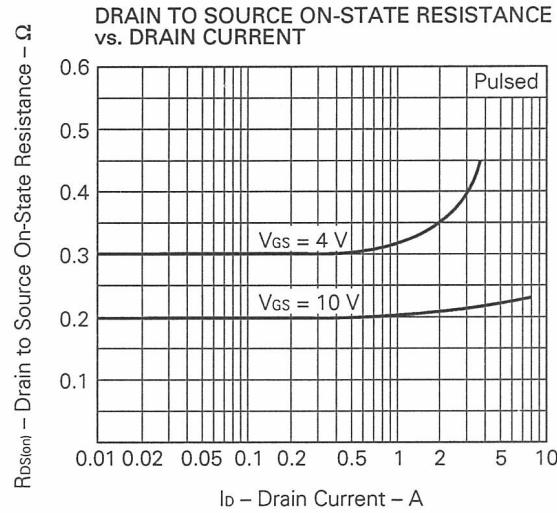
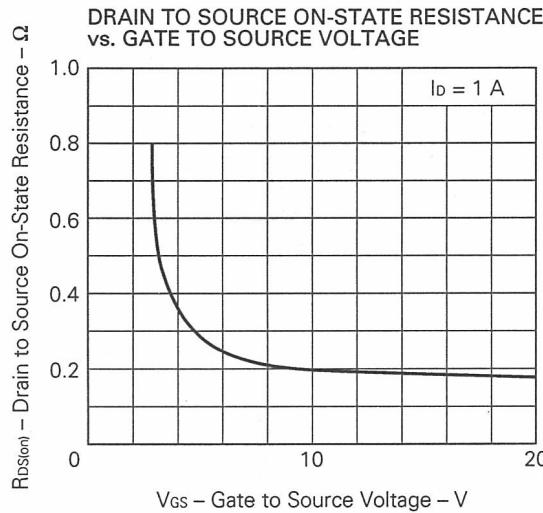
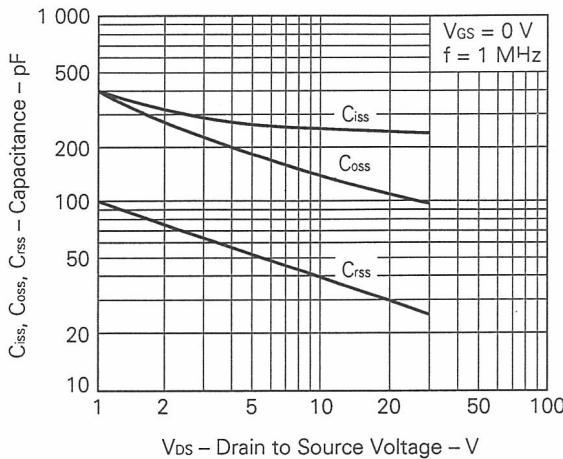
Fig. 1 Switching Time Test Circuit

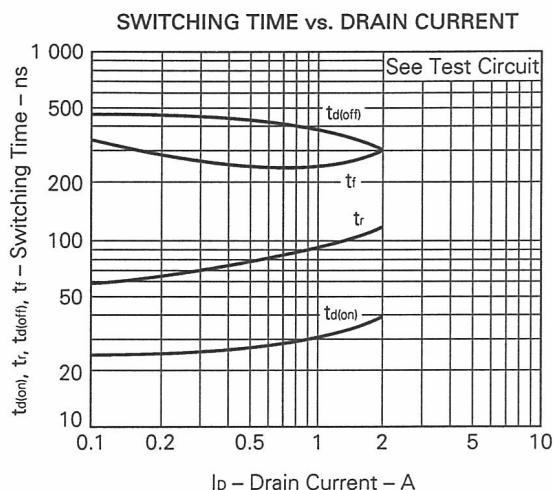
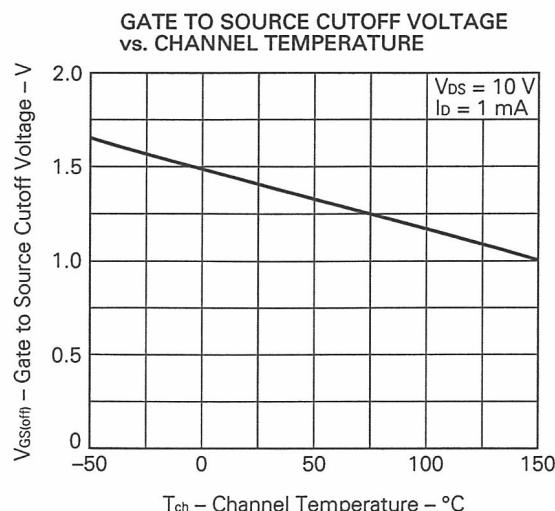
Phase-out/Discontinued**TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)**

SOURCE TO DRAIN DIODE FORWARD VOLTAGE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE





Reference

Document name	Document No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Safe operating area of Power MOS FET	TEA-1034
Appication circuit using Power MOS FET	TEA-1035

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